NSN 5962-01-448-4044

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View Online at https://aerobasegroup.com/nsn/5962-01-448-4044

Body Length:
1.375 inches
Body Width:
0.500 inches
Body Height:
0.185 inches
Maximum Power Dissipation Rating:
275.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
F-15 i
Features Provided:
Monolithic and ultraviolet erasable and programmable and electrostatic sensitive
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
23 input
Criticality Code Justification:
Cbbl
Case Outline Source And Designator:
D-10 mil-m-38510
Current Rating Per Characteristic:
25.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
14.0 volts power source
Memory Device Type:
Eprom
Special Features:
Altered item make from 5962-8606302xa configuration disc cp5363702, checksum fa75
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
28 printed circuit

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Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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